

Amendments to the Claims:

This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

Claim 1 (currently amended): A light-emitting device comprising: a first electrode, a layer including a light-emitting layer and a second electrode laminated in sequence on a substrate with a base layer in between, and extracting light generated in the light-emitting layer from the second electrode,

wherein the first electrode includes an adhesive layer disposed in contact with the base layer; a reflective layer disposed on the adhesive layer to reflect the light generated in the light-emitting layer; and a barrier layer disposed on the reflective layer to protect the reflective layer, wherein the reflective layer includes an alloy including silver (Ag) as a main component, about 0.03 % by mass to about 0.5 % by mass inclusive of samarium (Sm) and about 0.2 % by mass to about 1.0 % by mass inclusive of copper (Cu).

Claim 2 (original): The light-emitting device according to claim 1, wherein the adhesive layer is made of at least one of a metal, an electrically conductive oxide and a metal compound that include a metal element selected from the group consisting of chromium (Cr), indium (In), tin (Sn), zinc (Zn), cadmium (Cd), titanium (Ti), aluminum (Al), magnesium (Mg) molybdenum (Mo) and combinations thereof.

Claim 3 (original): The light-emitting device according to claim 1, wherein the reflective layer includes at least one of silver (Ag) and an alloy including silver.

Claim 4 (original): The light-emitting device according to claim 1, wherein the reflective layer is made of an alloy including silver (Ag) and a constituent selected from the group consisting of neodymium (Nd), samarium (Sm), yttrium (Y), cerium (Ce), europium (Eu), gadolinium (Gd), terbium (Tb), dysprosium (Dy), erbium (Er), ytterbium (Yb), scandium (Sc), ruthenium (Ru), copper (Cu), gold (Au) and combinations thereof.

claim 5 (original): The light-emitting device according to claim 1, wherein the reflective layer includes an alloy including silver (Ag), samarium (Sm) and copper (Cu).

Claim 6 (canceled)

Claim 7 (original): The light-emitting device according to claim 1, wherein the barrier layer includes a light-transparent film including at least one of a metal, an oxide and a metal compound including at least one kind selected from the group of metal elements consisting of indium (In), tin (Sn), zinc (Zn), cadmium (Cd), titanium (Ti), chromium (Cr), gallium (Ga) and aluminum (Al).

Claim 8 (original): The light-emitting device according to claim 1, wherein the barrier layer includes at least one kind selected from the group consisting of a compound including indium (In), tin (Sn) and oxygen (O), a compound including indium (In), zinc (Zn) and oxygen (O), indium tin oxide (ITO), indium zinc oxide (IZO), indium oxide (In_2O_3), tin oxide (SnO_2), zinc oxide (ZnO), cadmium oxide (CdO), titanium oxide (TiO_2), chromium oxide (CrO_2), gallium nitride (GaN), gallium oxide (Ga_2O_3) aluminum oxide (Al_2O_3) and combinations thereof.

Claim 9 (original): The light-emitting device according to claim 1, wherein the thickness of the barrier layer ranges from about 1 nm to about 50 nm inclusive.

Claim 10 (original): The light-emitting device according to claim 1, wherein the base layer includes a planarizing layer.

Claim 11 (original): The light-emitting device according to claim 1, wherein a layer including the light-emitting layer includes an organic layer.

Claim 12 (original): The light-emitting device according to claim 1, wherein the adhesive layer also serves as an auxiliary reflective film reflecting light generated in the light-emitting layer and having passed through the reflective layer.

Claim 13 (original): The light-emitting device according to claim 12, wherein the auxiliary reflective film includes at least one of a metal, an electrically conductive oxide, and a metal compound including at least one kind selected from the group of metal elements consisting of chromium (Cr), indium (In), tin (Sn), zinc (Zn), cadmium (Cd), titanium (Ti), aluminum (Al), magnesium (Mg) and molybdenum (Mo).

Claim 14 (original): The light-emitting device according to claim 12, wherein the auxiliary reflective film has a reflectance of about 50% or greater.

Claims 15 (canceled)

Claim 16 (currently amended): ~~The method of manufacturing a light emitting device according to claim 15~~ A method of manufacturing a light-emitting device, the light-emitting device comprising a first electrode, a layer including a light-emitting layer and a second electrode laminated in order on a substrate with a base layer in between, the method comprising the steps of:

forming an adhesive layer on the base layer;

forming a reflective layer reflecting light generated in the light-emitting layer on the adhesive layer;

forming a barrier layer protecting the reflective layer on the reflective layer;

forming the first electrode through patterning the barrier layer, the reflective layer and the adhesive layer in order from the barrier layer;

forming the layer including the light-emitting layer on the first electrode; and

forming the second electrode on the layer including the light-emitting layer, wherein

in the step of forming the first electrode, after the barrier layer and the reflective layer are patterned, the adhesive layer is patterned.

Claim 17 (currently amended): ~~The method of manufacturing a light-emitting device according to claim 15~~ A method of manufacturing a light-emitting device, the light-emitting device comprising a first electrode, a layer including a light-emitting layer and a second electrode laminated in order on a substrate with a base layer in between, the method comprising the steps of:

forming an adhesive layer on the base layer;

forming a reflective layer reflecting light generated in the light-emitting layer on the adhesive layer;

forming a barrier layer protecting the reflective layer on the reflective layer;

forming the first electrode through patterning the barrier layer, the reflective layer and the adhesive layer in order from the barrier layer;

forming the layer including the light-emitting layer on the first electrode; and

forming the second electrode on the layer including the light-emitting layer, wherein

in the step of forming the first electrode, after the barrier layer is patterned, the reflective layer and the adhesive layer are patterned.

Claim 18 (currently amended): ~~The method of manufacturing a light-emitting device according to claim 15~~ A method of manufacturing a light-emitting device, the light-emitting device comprising a first electrode, a layer including a light-emitting layer and a second electrode laminated in order on a substrate with a base layer in between, the method comprising the steps of:

forming an adhesive layer on the base layer;

forming a reflective layer reflecting light generated in the light-emitting layer on the adhesive layer;

forming a barrier layer protecting the reflective layer on the reflective layer;

forming the first electrode through patterning the barrier layer, the reflective layer and the adhesive layer in order from the barrier layer;

forming the layer including the light-emitting layer on the first electrode; and

forming the second electrode on the layer including the light-emitting layer, wherein

in the step of forming the first electrode, the barrier layer, the reflective layer and the adhesive layer are patterned one by one from the barrier layer.

Claims 19-22 (canceled)

Claim 23 (currently amended): ~~The method of manufacturing a light-emitting device according to claim 15~~ A method of manufacturing a light-emitting device, the light-emitting device comprising a first electrode, a layer including a light-emitting layer and a second electrode laminated in order on a substrate with a base layer in between, the method comprising the steps of:

forming an adhesive layer on the base layer;

forming a reflective layer reflecting light generated in the light-emitting layer on the adhesive layer;

forming a barrier layer protecting the reflective layer on the reflective layer;

forming the first electrode through patterning the barrier layer, the reflective layer and the adhesive layer in order from the barrier layer;

forming the layer including the light-emitting layer on the first electrode; and

forming the second electrode on the layer including the light-emitting layer, wherein

the reflective layer includes an alloy including silver (Ag) as a main component, about 0.03 % by mass to about 0.5 % by mass inclusive of samarium (Sm) and about 0.2 % by mass to about 1.0 % by mass inclusive of copper (Cu).

Claims 24-29 (canceled)